

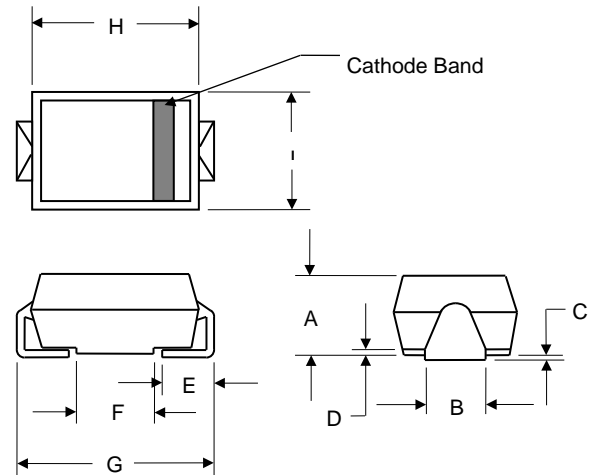
Features

- * For surface mounted application
- * Low Forward Voltage Drop
- * High Current Capability
- * Easy Pick and Place
- * High Surge Current Capability
- * Plastic Material Used Carries Underwriters Laboratory Classification 94V-0



Package Outline Dimensions in inches (millimeters)

SMA(W):



DIM	INCHES		MM	
	MIN	MAX	MIN	MAX
A	.078	.116	1.98	2.95
B	.067	.089	1.70	2.25
C	.002	.008	0.05	0.20
D	-----	.020	-----	0.51
E	.035	.055	0.89	1.40
F	.065	.091	1.65	2.32
G	.205	.224	5.21	5.69
H	.160	.180	4.06	4.57
J	.100	.112	2.57	2.84

Mechanical Data

- * Case: DO-214AC Molded plastic
- * Terminals: Solder plated
- * Polarity: Indicated by cathode band
- * Standard packaging: 12mm tape(ELA STD RS-481)

Maximum Ratings and Electrical Characteristics

Rating at 25 °C ambient temperature unless otherwise specified. Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Type Number	Symbols	M1	M2	M3	M4	M5	M6	M7	Unit
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	V_{RMS}	35	70	140	280	420	560	700	V
Maximum D.C Blocking Voltage	V_{DC}	50	100	200	400	600	800	1000	V
Maximum Average Forward Rectified Current $T_L=75^{\circ}C$	$I_{F(AV)}$	1.0							A
Peak Forward Surge Current, 8.3ms single half sine-wave	I_{FSM}	30							A
Maximum Instantaneous Forward Voltage at 1.0A	V_F	1.1							V
Maximum D.C Reverse Current @ $T_A=25^{\circ}C$ at Rated D.C Blocking Voltage @ $T_A=100^{\circ}C$	I_R	5.0 50							μA
Maximum Reverse Recovery Time(Note1)	T_{rr}	1.8							μS
Typical Junction Capacitance(Note2)	C_J	8							pF
Operating and Storage Temperature Range	T_J/T_{STG}	-55 to +125/-55 to +150							$^{\circ}C$

Note: 1、 Reverse Recovery Test Conditions: $I_F=0.5A$, $I_R=1.0A$, $I_{RR}=0.25A$. 2、 Measured at 1MHz and applied reverse voltage of 4.0V D.C.

Ratings and Characteristic Curves

FIG. 1 – FORWARD CURRENT DERATING CURVE

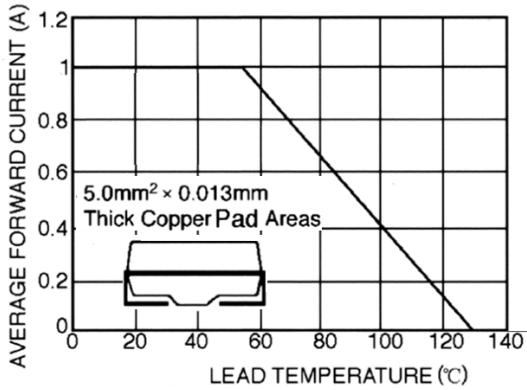


FIG. 2 – MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

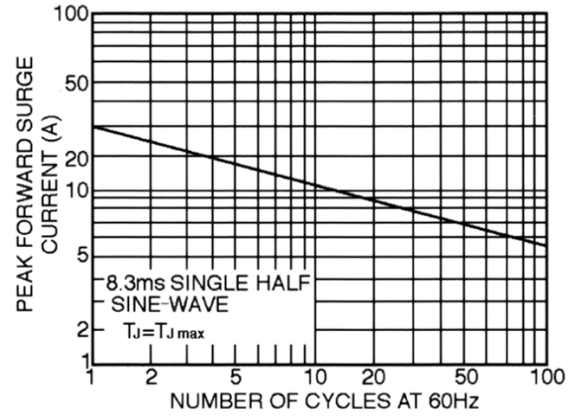


FIG. 3 – TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

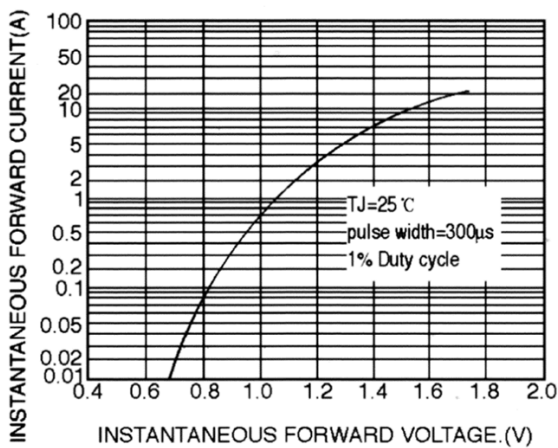


FIG. 4 – TYPICAL JUNCTION CAPACITANCE

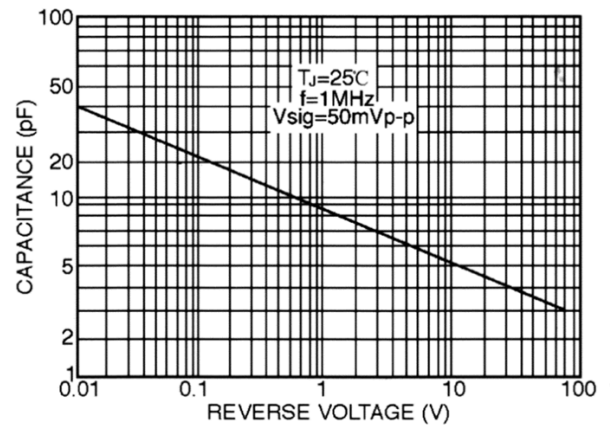
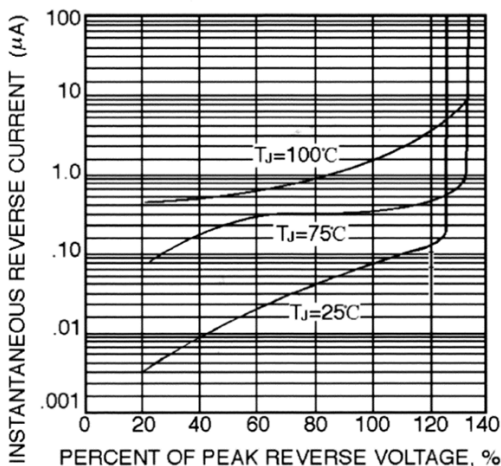


FIG. 5 – TYPICAL REVERSE CHARACTERISTICS





M1 THRU M7
1.0 Amp. Surface Mount Rectifiers

Ordering Information

Part No.	Package	Packing
M1~M7	SMA(W)	5K/Reel
M1~M7	SMA(W)	6K/Reel
M1~M7	SMA(W)	7.5K/Reel

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